



# 1N914

Small-Signal Diode  
Fast Switching Diode

## Features

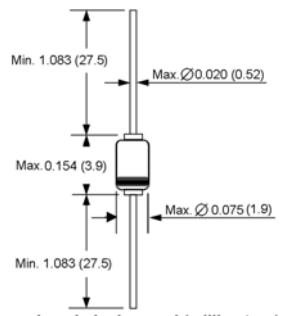
- ◆ Silicon Epitaxial Planar Diode
- ◆ For general purpose and switching



DO-204AH (DO-35 Glass)

## Mechanical Data

- ◆ Case: DO-34, DO-35 Glass Case
- ◆ Weight: approx. 0.13g



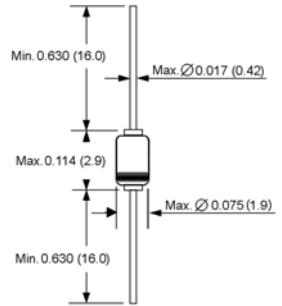
Dimensions in inches and (millimeters)

DO-34 Glass

## Maximum Ratings and Thermal Characteristics

( $T_A=25^\circ\text{C}$  unless otherwise noted.)

| Parameter                                       | Symbol      | Limit | Unit  |
|---|-------------|-------|-------|
| Peak reverse voltage                            | $V_{RM}$    | 100   | Volts |
| Average rectified current                       | $I_{F(AV)}$ | 75    | mA    |
| Power dissipation at $T_{amb}=25^\circ\text{C}$ | $P_{tot}$   | 500   | mW    |
| Junction temperature                            | $T_J$       | 175   | °C    |



Dimensions in inches and (millimeters)

## Electrical Characteristics

( $T_J=25^\circ\text{C}$  unless otherwise noted.)

| Parameter             | Symbol    | Test Condition   | Min. | Typ. | Max.      | Unit     |
|-----------------------|-----------|--|------|------|-----------|----------|
| Forward voltage drop  | $V_F$     | $I_F=10\text{mA}$  | -    | -    | 1.0       | Volt     |
| Reverse current       | $I_R$     | $V_R=20\text{V}$<br>$V_R=75\text{V}$   | -    | -    | 25<br>5.0 | nA<br>uA |
| Reverse recovery time | $t_{rr}$  | $I_F=I_R=10\text{mA}$ , $V_R=6\text{V}$<br>$R_L=100\Omega$ , to $I_F=1\text{mA}$ | -    | -    | 4.0       | ns       |
| Capacitance           | $C_{tot}$ | $V_R=0$ , $f=1.0\text{MHz}$  | -    | -    | 4.0       | pF       |